16-BIT BUS SWITCH

FEATURES:

- · Bus switches provide zero delay paths
- · Low switch on-resistance
- TTL-compatible input and output levels
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- · Hot insertion capability
- · Very low power dissipation
- · Available in SSOP and TSSOP packages

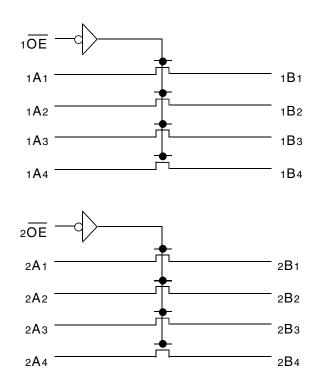
DESCRIPTION:

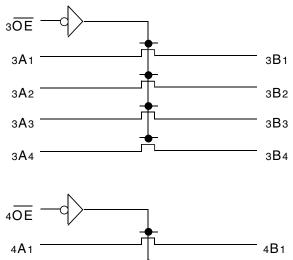
The FST163244 belongs to IDT's family of Bus switches. Bus switch devices perform the function of connecting or isolating two ports without providing any inherent current sink or source capability. They generate little or no noise of their own while providing a low resistance path for an external driver. These devices connect input and output ports through an n-channel FET. When the gate-to-source junction of this FET is adequately forward-biased, the device conducts and the resistance between input and output ports is small. Without adequate bias on the gate-to-source junction of the FET, the FET is turned off, therefore with no Vcc applied, the device has hot insertion capability.

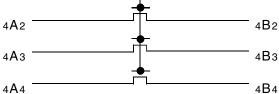
The low on-resistance and simplicity of the connection between input and output ports reduces the delay in this path to close to zero.

The FST163244 is pin-compatible with and functionally similar to the FCT16244T.

FUNCTIONAL BLOCK DIAGRAM







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PINCONFIGURATION

	1		л <i>Г</i>		1	
10E		1	\bigcirc	48		2 0E
1B1		2		47		1 A 1
1B2		3		46		1 A 2
GND		4		45		GND
1 B 3		5		44		1 A 3
1 B 4		6		43		1 A 4
Vcc		7		42		Vcc
2B1		8		41		2 A 1
2B2		9		40		2 A 2
GND		10		39		GND
2 B 3		11		38		2 A 3
2 B 4		12		37		2 A 4
3 B 1		13		36		3 A 1
3 B 2		14		35		3 A 2
GND		15		34		GND
зВз		16		33		зАз
3 B 4		17		32		3 A 4
Vcc		18		31		Vcc
4B1		19		30		4 A 1
4B2		20		29		4 A 2
GND		21		28		GND
4 B 3		22		27		4 A 3
4B4		23		26		4 A 4
4 <mark>0E</mark>		24		25		з <mark>ОЕ</mark>
					I	

SSOP/ TSSOP TOP VIEW

INDUSTRIAL TEMPERATURE RANGE

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	–0.5 to +7	V
Tstg	Storage Temperature	-65 to +150	°C
Ιουτ	Maximum Continuous Channel Current	128	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc, Control, and Switch terminals.

CAPACITANCE⁽¹⁾

Symbol	Parameter	Conditions ⁽²⁾	Тур.	Unit
CIN	Control Input Capacitance		6	рF
Ci/o	Switch Input/Output Capacitance	Switch Off	12	pF

NOTES:

1. Capacitance is characterized but not tested.

2. $T_A = 25^{\circ}C$, f = 1MHz, $V_{IN} = 0V$, $V_{OUT} = 0V$.

PIN DESCRIPTION

Pin Names	Description
xŌĒ	Output Enable Inputs (Active LOW)
хАх	A Port Bits
хВх	B Port Bits

FUNCTION TABLE⁽¹⁾

Inputs	
xOE	Outputs
L	Connect A to B
Н	Disconnect A from B

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

 $\label{eq:conditions} Following \, Conditions \, Apply \, Unless \, Otherwise \, Specified:$

Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = 5.0V $\pm 10\%$

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Тур. ⁽²⁾	Max.	Unit
Vih	Control Input HIGH Voltage	Guaranteed Logic HIGH for	or Control Inputs	2	_	_	V
Vil	Control Input LOW Voltage	Guaranteed Logic LOW for	r Control Inputs	-	_	0.8	V
Ін	Control Input HIGH Current	Vcc = Max.	VI = VCC	-	-	±1	μA
lil	Control Input LOW Current		VI = GND	-	_	±1	
Іоzн	Current During	Vcc = Max., Vo = 0 to 5V	Vcc = Max., Vo = 0 to 5V		_	±1	μA
Iozl	Bus Switch Disconnect				—	±1	
νικ	Clamp Diode Voltage	Vcc = Min., IIN = -18mA	Vcc = Min., IIN = -18mA		-0.7	-1.2	V
IOFF	Switch Power Off Leakage	Vcc = 0V, VIN or Vo ≤ 5.5 V		_	_	±1	μA
lcc	Quiescent Power Supply Current	Vcc = Max., VIN = GND c	or Vcc	—	0.1	3	μA

BUS SWITCH IMPEDANCE OVER OPERATING RANGE

 $Following \, Conditions \, Apply \, Unless \, Otherwise \, Specified:$

Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = $5.0V \pm 10\%$

Symbol	Parameter	Test Conditions	Min.	Тур. ⁽¹⁾	Max.	Unit
Ron	Switch On Resistance, A to B ⁽²⁾	Vcc = Min., $Vin = 0V$, $Ion = 12mA$	_	5	7	Ω
		Vcc = Min., Vin = 2.4V, Ion = 8mA	—	10	15	
los	Short Circuit Current, A to B ⁽³⁾	A(B) = 0V, B(A) = Vcc	100	—	—	mA

NOTES:

1. Typical values are at Vcc = 5.0V, +25°C ambient.

2. The voltage drop between the indicated ports divided by the current through the switch.

3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditi	ons ⁽¹⁾	Min.	Тур. ⁽²⁾	Max.	Unit
∆lcc	Quiescent Power Supply Current TTL Inputs HIGH	Vcc = Max. VIN = 3.4V ⁽³⁾			0.5	1.5	mA
ICCD	Dynamic Power Supply Current ^(4,5)	Vcc = Max. One Enable Pin Toggling 50% Duty Cycle	VIN = VCC VIN = GND		120	160	μΑ/ MHz/ Enable
lc	Total Power Supply Current ⁽⁶⁾	Vcc = Max. One Enable Pin Toggling	VIN = VCC VIN = GND	-	1.2	1.6	mA
		fi = 10MHz 50% Duty Cycle	VIN = VCC VIN = 3.4V	—	1.5	2.4	
		Vcc = Max. Four Enable Pins Toggling	Vin = Vcc Vin = GND		4.8	6.4	
		fi = 10MHz 50% Duty Cycle	VIN = VCC VIN = 3.4V	_	5.8	9.4	

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type. Ta = -40°C to +85°C

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Per TTL driven input (VIN = 3.4V). All other inputs at Vcc or GND. Switch inputs do not contribute to Δ Icc.

4. This parameter represents the current required to switch the internal capacitance of the control inputs at the specified frequency.

Switch inputs generate no significant power supply currents as they transition. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations. 5. CPD = IccD/Vcc

CPD = Power Dissipation Capacitance

- 6. IC = IQUIESCENT + INPUTS + IDYNAMIC
- $IC = ICC + \Delta ICC DHNT + ICCD (fiN)$
- Icc = Quiescent Current

 Δ Icc = Power Supply Current for a TTL High Input (VIN = 3.4V)

DH = Duty Cycle for TTL Inputs High

 $\mathsf{N}\mathsf{T}$ = Number of TTL Inputs at $\mathsf{D}\mathsf{H}$

ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

fi = Control Input Frequency

N = Number of Control Inputs Toggling at fi

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $\label{eq:Following} \ Conditions \ Apply \ Unless \ Otherwise \ Specified:$

Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = 5.0V $\pm 10\%$

			$Vcc = 5V \pm 10\%$			
Symbol	Description ⁽¹⁾	Min.	Тур.	Max.	Max.	Unit
t PLH	Data Propagation Delay	_	—	0.25	0.25	ns
t PHL	A to B, B to A ⁽²⁾					
tрzн	Switch CONNECT Delay	1.5	—	5.6	—	ns
t PZL	xOE to A or B					
tрнz	Switch DISCONNECT Delay	1.5	—	5.2	—	ns
t PLZ	xOE to A or B					
Qci	Charge Injection During Switch DISCONNECT	_	1.5	_	_	рС
	$x\overline{OE}$ to A or B ⁽³⁾					

NOTES:

1. See test circuits and waveforms.

2. The bus switch contributes no Propagation Delay other than the RC Delay of the load interacting with the RC of the switch.

3. [Qci] is the charge injection for a single switch DISCONNECT and applies to either single switches or multiplexers. Charge injection is reduced because the injection from the DISCONNECT of the first path is compensated by the CONNECT of the second path.

IDT74FST163244 16-BIT BUS SWITCH

TEST CIRCUITS AND WAVEFORMS

Propagation Delay

Test Circuits for All Outputs

SWITCH POSITION

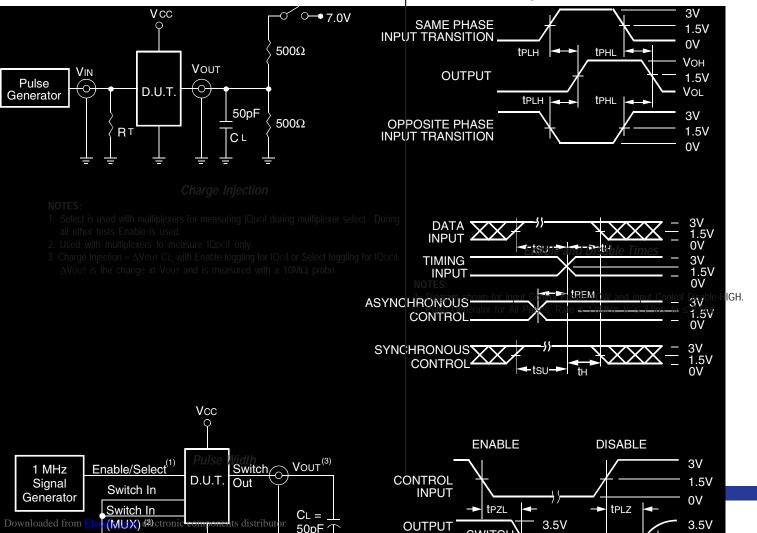
Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

DEFINITIONS:

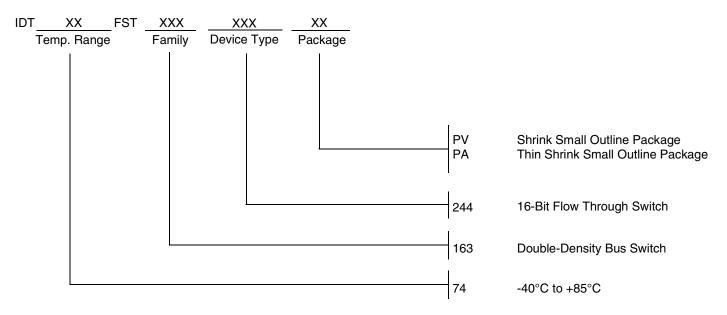
CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

Set-up, Hold, and Release Times



ORDERING INFORMATION





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